

## N-CHANNEL J-FET

Equivalent To MIL-PRF-19500/385

### DEVICES

**2N4856 2N4858 2N4860**  
**2N4857 2N4859 2N4861**

### LEVELS

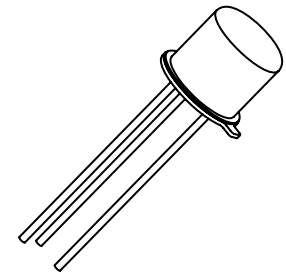
**MQ = JAN Equivalent**  
**MX = JANTX Equivalent**  
**MV = JANTXV Equivalent**

### ABSOLUTE MAXIMUM RATINGS ( $T_C = +25^\circ\text{C}$ unless otherwise noted)

Parameters / Test Conditions	Symbol	2N4856	2N4859	Unit
		2N4857	2N4860	
		2N4858	2N4861	
Gate-Source Voltage	$V_{GS}$	-40	-30	V
Drain-Source Voltage	$V_{DS}$	40	30	V
Drain-Gate Voltage	$V_{DG}$	40	30	V
Gate Current	$I_G$	50		mA
Power Dissipation	$P_T$	$T_A = +25^\circ\text{C}^{(1)}$		W
		$T_C = +25^\circ\text{C}^{(2)}$		W
Operating Junction & Storage Temperature Range	$T_J, T_{stg}$	-65 to + 200		$^\circ\text{C}$

(1) Derate linearly 2.06 mW/ $^\circ\text{C}$  for  $T_A > +25^\circ\text{C}$ .

(2) Derate linearly 10.3 mW/ $^\circ\text{C}$  for  $T_C > +25^\circ\text{C}$ .



**TO-18**  
**(TO-206AA)**

### ELECTRICAL CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ , unless otherwise noted)

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Gate-Source Breakdown Voltage $V_{DS} = 0, I_G = -1.0\mu\text{A dc}$	$V_{(BR)GS}$	2N4856, 2N4857, 2N4858	-40	Vdc
		2N4859, 2N4860, 2N4861	-30	
Gate-Source "Off" State Voltage $V_{DS} = 15\text{V dc}$ $I_D = 0.5\eta\text{A dc}$	$V_{GS(off)}$	2N4856, 2N4859	-4.0	Vdc
		2N4857, 2N4860	-2.0	
		2N4858, 2N4861	-0.8	
Gate Reverse Current $V_{DS} = 0, V_{GS} = -20\text{V dc}$ $V_{DS} = 0, V_{GS} = -15\text{V dc}$	$I_{GSS}$	2N4856, 2N4857, 2N4858	-0.25	$\eta\text{A}$
		2N4859, 2N4860, 2N4861	-0.25	
Drain Current Cutoff $V_{GS} = -10\text{V dc}, V_{DS} = 15\text{V dc}$	$I_{D(off)}$		0.25	$\eta\text{A}$
Drain Current Zero Gate Voltage $V_{GS} = 0, V_{DS} = 15\text{V dc}$	$I_{DSS}$	2N4856, 2N4859	50	mA
		2N4857, 2N4860	20	
		2N4858, 2N4861	8.0	
Drain-Source "On" State Voltage $V_{GS} = 0, I_D = 20\text{mA dc}$ $V_{GS} = 0, I_D = 10\text{mA dc}$ $V_{GS} = 0, I_D = 5.0\text{mA dc}$	$V_{DS(on)}$	2N4856, 2N4859	0.75	Vdc
		2N4857, 2N4860	0.50	
		2N4858, 2N4861	0.50	
Static Drain - Source "On" State Resistance $V_{GS} = 0, I_D = 1.0\text{mA dc}$	$r_{ds(on)}$	2N4856, 2N4859	25	$\Omega$
		2N4857, 2N4860	40	
		2N4858, 2N4861	60	



6 Lake Street, Lawrence, MA 01841  
 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803  
 Website: <http://www.microsemi.com>

# TECHNICAL DATA SHEET

## N-CHANNEL J-FET Equivalent To MIL-PRF-19500/385

### DYNAMIC CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Small-Signal, Common Short-Circuit Reverse Transfer Capacitance $V_{GS} = -10V$ dc, $V_{DS} = 0$ , $f = 1.0MHz$ $C_1 = 0.1\mu F$ , $L_1 = L_2 \geq 500\mu H$	$C_{rss}$		8.0	pF
Small-Signal, Common-Source Short-Circuit Input Capacitance $V_{GS} = -10V$ dc, $V_{DS} = 0$ , $f = 1.0MHz$ $C_1 = 0.1\mu F$ , $C_2 = 20.1\mu F$ $L_1 = L_2 \geq 500\mu H$	$C_{iss}$		18	pF

### SWITCHING CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Turn-On Delay Time 2N4856, 2N4859 2N4857, 2N4860 2N4858, 2N4861	See Figure 3 of MIL-PRF-19500/385		6	$\eta s$
Rise Time 2N4856, 2N4859 2N4857, 2N4860 2N4858, 2N4861			3 4 10	
Turn-Off Delay Time 2N4856, 2N4859 2N4857, 2N4860 2N4858, 2N4861			25 50 100	